

捷多邦, 专业PCB打样工厂, 24小时加急出货 HT9201A/B Simple Tone Dialer

Features

Patent Number: 113235(R.O.C.), 5424740(U.S.A.)

- Operating voltage: 2.0V~5.5V
- Low standby current
- 4×4 keyboard matrix

General Description

The HT9201A/B tone dialers are CMOS LSIs designed for telecommunication systems. The HT9201A is for mute output whereas the HT9201B is for flash output. Both dialers pro-

• 3.58MHz crystal or ceramic resonator

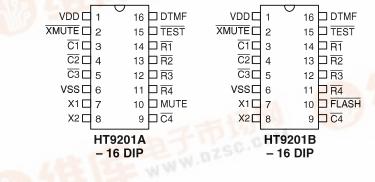
• Four flash key times selectable for the HT9201B

vide good performance for regular DTMF dialing with low distortion output and minimal external components.

Selection Table

Function		XMUTE	F1,F2,F3,F4	A,B,C,D	Dealer
Item	MUTE	XIVUTE	Flash Time (ms)	DTMF Output	Package
HT9201A	\checkmark	\checkmark	_	\checkmark	16 DIP
HT9201B	_	\checkmark	600/300/200/90	a - G	16 DIP





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Keyboard Information

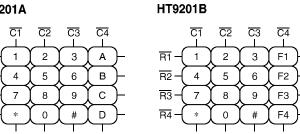
HT9201A

R1

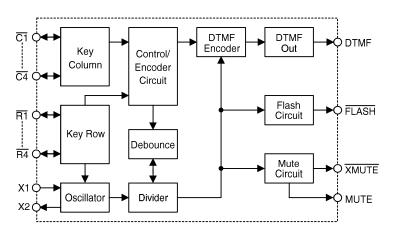
R2 -

R3-

R4



Block Diagram



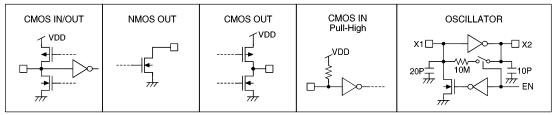
Pin Description

Pin Name	I/O	Internal Connection	Description		
$\frac{\overline{C1}}{\overline{R1}} \sim \overline{C4}$	I/O	CMOS IN/OUT	These pins form a 4×4 keyboard matrix which can perform keyboard input detection and dialing specification setting functions. When the chip is in the standby mode the column group ($\overline{C1}$ ~ $\overline{C4}$) remains low whereas the row group ($\overline{R1}$ ~ $\overline{R4}$) is set high for key input detection. An inexpensive single contact 4×4 keyboard can be used as an input device. Pressing a key connects a single column to a single row, and actuates the system oscillator which result in a dialing signal output. If more than two keys are pressed at a time, no response occurs. The key-in debounce time is 20ms. Refer to the keyboard information for keyboard arrangement.		



Pin Name	I/O	Internal Connection	Description
X1	Ι	OSCILLATOR	The system oscillator consists of an inverter, a bias resistor and the necessary load capacitor on chip. Connecting a standard 3.579545MHz crystal or ceramic resonator to the X1
X2	0		and X2 terminals can implement the oscillator function. The oscillator is turned off in the standby mode, and is actuated whenever a keyboard entry is detected.
XMUTE	0	NMOS OUT	XMUTE is an NMOS open drain structure pulled to VSS during dialing signal transmission. Otherwise, it is an open circuit. XMUTE is used to mute the speech circuit when transmitting the dial signal.
MUTE	0	CMOS OUT	The output is low when no keypad input is entered and it becomes high during dialing sequence. The timing diagram is shown in the operation timing.
FLASH	0	CMOS OUT	This pin is a CMOS output structure from which the chip receives the flash key (F1 \sim F4) signals to break the telephone line for a flash time.
TEST	Ι	CMOS IN Pull-High	For IC chip test only
VDD	Ι		Positive power supply, 2.0V~5.5V for normal operation
VSS	Ι		Negative power supply

Approximate internal connection circuits



Absolute Maximum Ratings*

Supply Voltage -0.3V to 6V

Input Voltage VSS-0.3V to VDD+0.3V

Storage Temperature -50°C to 125°C Operating Temperature -20°C to 75°C

*Note: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied and exposure to absolute maximum rating conditions for extended periods may affect device reliability.



Electrical Characteristics

Course hal	Devenator	Test Conditions		Min	T	Mart	T
Symbol	Parameter	V _{DD}	Conditions	Min.	Тур.	Max.	Unit
V _{DD}	Operating Voltage			2	_	5.5	V
I _{DD}	Operating Current	2.5V	Keypad entry No load	_	0.6	2	mA
I _{STB}	Standby Current	2.5V	No load, no entry	_	_	1	μΑ
VIL	Input Low Voltage		_	V _{SS}	_	0.2V _{DD}	V
VIH	Input High Voltage		_	0.8V _{DD}	_	VDD	V
I _{XMO}	XMUTE Leakage Current	_	V XMUTE =12V No entry			1	μA
IOLXM	XMUTE Sink Current	2.5V	VXMUTE=0.5V	1	_	_	mA
IOH1	Keypad Pin Source Current	2.5V	V _{OH} =0V	-4	_	-40	μΑ
I _{OL1}	Keypad Pin Sink Current	2.5V	Vol=2.5V	200	400	_	μA
T _{DB}	Key-in Debounce Time		F _{OSC} =3.5795MHz	_	20	_	ms
Fosc	System Frequency		Crystal=3.5795MHz	3.5759	3.5795	3.5831	MHz

Tone Mode Electrical Characteristics

(Fosc=3.5795MHz, Ta= 25° C)

Symbol	Donomoton	Parameter Test Condition		Min.	Tun	Max.	Unit
Symbol	r al ameter	V _{DD}	Conditions	WIIII.	Тур.	wax.	Um
VTDC	DTMF Output DC Level	_	—	$0.45 V_{DD}$		0.7V _{DD}	V
I _{TOL}	DTMF Sink Current	2.5V	V _{DTMF} =0.5V	0.1		_	mA
VTAC	DTMF Output AC Level	—	Row group, $R_L=5k\Omega$	0.12	0.155	0.18	Vrms
RL	DTMF Output Load	2.5V	THD≤–23dB	5			kΩ
ACR	Column Pre-emphasis	2.5V	Row group=0dB	1	2	3	dB
THD	DTMF Signal Distortion	2.5V	$R_L=5k\Omega$		-30	-23	dB

THD (Distortion) (dB) = 20 log ($\sqrt{V1^2 + V2^2 + ... + Vn^2}$ / $\sqrt{Vi^2 + Vh^2}$)

Vi, Vh: Row group and column group signals

V1, V2, ... Vn: Harmonic signals (BW=300Hz~3500Hz)





Functional Description

Keyboard matrix

 $\overline{C1}$ ~ $\overline{C4}$ and $\overline{R1}$ ~ $\overline{R4}$ form a keyboard matrix. The keyboard arrangement for each of the HT9201 series are shown in the Keyboard Information.

Tone frequency

Tone Name	Outj Frequen	% Error	
Ivame	Specified	Actual	
R1	697	699	+0.29%
R2	770	766	-0.52%
R3	852	847	-0.59%
R4	941	948	+0.74%
C1	1209	1215	+0.50%
C2	1336	1332	-0.30%
C3	1477	1472	-0.34%
C4	1633	1645	+0.73%

Note: % Error does not contain the crystal frequency drift

Key definition

FLASH

- 0, 1, 2, 3, 4, 5, 6, 7, 8, 9, *, #, A, B, C, D keys These are the dialing number input keys for normal operation.
- **Timing Diagrams** High Impedance KEY IN -D1 D2 F D3 TDB ► TDB ► ➡ TDB ≁ XMUTE MUTE -~~~ DTMF X2

• F1, F2, F3, F4

The flash keys can be selected with different flash times as shown in the following table.

Flash time selection table

Key	Flash Time (ms)
F1	600
F2	300
F3	200
F4	90

Keyboard operation

- (a) without flash key Keyboard input: D1 D2 ... Dn Dialing output: D1 D2 ... Dn
- (b) with flash key (F1/F2/F3/F4) Keyboard input: D1 D2 ... Dn F Dn+1 ... Dm (Note: F=F1/F2/F3/F4) Dialing output: D1 D2 ... Dn TF (break a flash time)

Dn+1 ... Dm

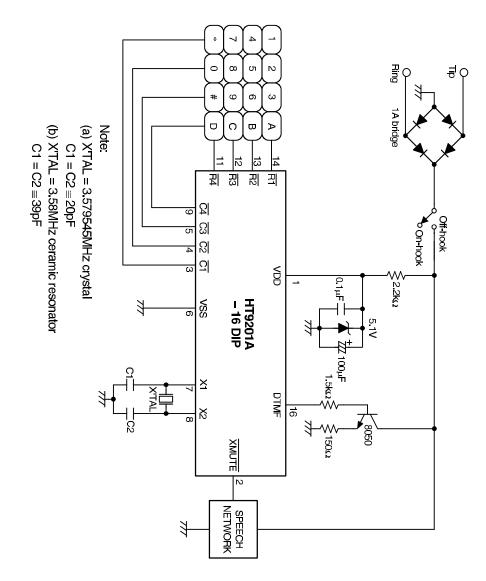
Flash time



HT9201A/B

Application Circuits

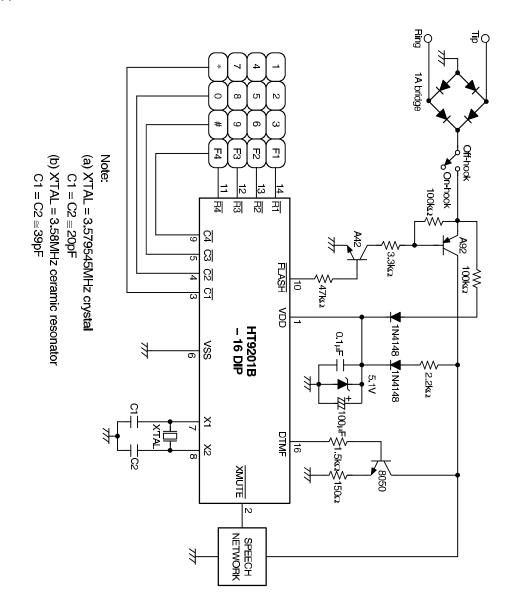
Application circuit 1



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Application circuit 2



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